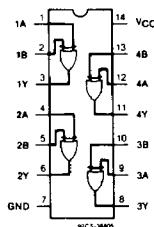


Advance Information

FUNCTIONAL DIAGRAM &
TERMINAL ASSIGNMENT

The RCA CD54/74AC86 and CD54/74ACT86 quad 2-input Exclusive-OR gates use the RCA ADVANCED CMOS technology. The CD74AC86 and CD74ACT86 are supplied in 14-lead dual-in-line plastic packages (E suffix) and in 14-lead dual-in-line small-outline plastic packages (M suffix). Both package types are operable over the following temperature ranges: Commercial (0 to 70°C); Industrial (-40 to +85°C); and Extended Industrial/Military (-55 to +125°C).

The CD54AC86 and CD54ACT86, available in chip form (H suffix), are operable over the -55 to +125°C temperature range.

TRUTH TABLE

INPUTS		OUTPUT
nA	nB	nY
L	L	L
H	H	L
H	L	H
L	H	H

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY-VOLTAGE (V _{cc})	-0.5 to 6 V
DC INPUT DIODE CURRENT, I _{in} (for V _i < -0.5 V or V _i > V _{cc} + 0.5 V)	±20 mA
DC OUTPUT DIODE CURRENT, I _{ox} (for V _o < -0.5 V or V _o > V _{cc} + 0.5 V)	±50 mA
DC OUTPUT SOURCE OR SINK CURRENT per Output Pin, I _o (for V _o > -0.5 V or V _o < V _{cc} + 0.5 V)	±50 mA
DC V _{cc} or GROUND CURRENT (I _{cc} or I _{GND})	±100 mA*
POWER DISSIPATION PER PACKAGE (P _d):	
For T _A = -55 to +100°C (PACKAGE TYPE E)	500 mW
For T _A = +100 to +125°C (PACKAGE TYPE E)	Derate Linearly at 8 mW/°C to 300 mW
For T _A = -55 to +70°C (PACKAGE TYPE M)	400 mW
For T _A = +70 to +125°C (PACKAGE TYPE M)	Derate Linearly at 6 mW/°C to 70 mW
OPERATING-TEMPERATURE RANGE (T _A):	-55 to +125°C
STORAGE TEMPERATURE (T _{stg})	-65 to +150°C
LEAD TEMPERATURE (DURING SOLDERING):	
At distance 1/16 ± 1/32 in. (1.59 ± 0.79 mm) from case for 10 s maximum	+265°C
Unit inserted into PC board min. thickness 1/16 in. (1.59 mm) with solder contacting lead tips only	+300°C

* For up to 4 outputs per device; add ± 25 mA for each additional output.

CD54/74AC86

CD54/74ACT86

RECOMMENDED OPERATING CONDITIONS:

For maximum reliability, normal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	LIMITS		UNITS
	MIN.	MAX.	
Supply-Voltage Range, V_{cc} *: (For T_A = Full Package-Temperature Range)	1.5	5.5	V
AC Types	4.5	5.5	V
ACT Types			
DC Input or Output Voltage, V_I , V_O	0	V_{cc}	V
Operating Temperature, T_A :	-55	+125	°C
Input Rise and Fall Slew Rate, dt/dv	0	50	ns/V
at 1.5 V to 3 V (AC Types)	0	20	ns/V
at 3.6 V to 5.5 V (AC Types)	0	10	ns/V
at 4.5 V to 5.5 V (ACT Types)			

*Unless otherwise specified, all voltages are referenced to ground.

STATIC ELECTRICAL CHARACTERISTICS: AC Series

CHARACTERISTICS	TEST CONDITIONS		V_{cc} (V)	AMBIENT TEMPERATURE (T_A) - °C						UNITS	
				+25		-40 to +85		-55 to +125			
	V_I (V)	I_O (mA)		MIN.	MAX.	MIN.	MAX.	MIN.	MAX.		
High-Level Input Voltage	V_{IH}		1.5	1.2	—	1.2	—	1.2	—	V	
			3	2.1	—	2.1	—	2.1	—		
			5.5	3.85	—	3.85	—	3.85	—		
Low-Level Input Voltage	V_{IL}		1.5	—	0.3	—	0.3	—	0.3	V	
			3	—	0.9	—	0.9	—	0.9		
			5.5	—	1.65	—	1.65	—	1.65		
High-Level Output Voltage	V_{OH}	V_{IH} or V_{IL} $\#$, *	-0.05	1.5	1.4	—	1.4	—	1.4	V	
			-0.05	3	2.9	—	2.9	—	2.9		
			-0.05	4.5	4.4	—	4.4	—	4.4		
			-4	3	2.58	—	2.48	—	2.4		
			-24	4.5	3.94	—	3.8	—	3.7		
			-75	5.5	—	—	3.85	—	—		
			-50	5.5	—	—	—	—	3.85		
Low-Level Output Voltage	V_{OL}	V_{IH} or V_{IL} $\#$, *	0.05	1.5	—	0.1	—	0.1	—	V	
			0.05	3	—	0.1	—	0.1	—		
			0.05	4.5	—	0.1	—	0.1	—		
			12	3	—	0.36	—	0.44	—		
			24	4.5	—	0.36	—	0.44	—		
			75	5.5	—	—	—	1.65	—		
			50	5.5	—	—	—	—	1.65		
Input Leakage Current	I_I	V_{cc} or GND		5.5	—	±0.1	—	±1	—	μA	
Quiescent Supply Current, SSI	I_{cc}	V_{cc} or GND	0	5.5	—	4	—	40	—	80	μA

#Test one output at a time for a 1-second maximum duration. Measurement is made by forcing current and measuring voltage to minimize power dissipation.

*Test verifies a minimum 50-ohm transmission-line-drive capability at +85°C, 75 ohms at +125°C.

CD54/74AC86
CD54/74ACT86

STATIC ELECTRICAL CHARACTERISTICS: ACT Series

CHARACTERISTICS	TEST CONDITIONS		V _{CC} (V)	AMBIENT TEMPERATURE (T _A) - °C						UNITS	
				+25		-40 to +85		-55 to +125			
	V _I (V)	I _O (mA)		MIN.	MAX.	MIN.	MAX.	MIN.	MAX.		
High-Level Input Voltage	V _{IH}		4.5 to 5.5	2	—	2	—	2	—	V	
Low-Level Input Voltage	V _{IL}		4.5 to 5.5	—	0.8	—	0.8	—	0.8	V	
High-Level Output Voltage	V _{OH}	V _{IH} or V _{IL} #, *	-0.05	4.5	4.4	—	4.4	—	4.4	—	
			-24	4.5	3.94	—	3.8	—	3.7	—	
			-75	5.5	—	—	3.85	—	—	—	
			-50	5.5	—	—	—	—	3.85	—	
Low-Level Output Voltage	V _{OL}	V _{IL} or V _{IL} #, *	0.05	4.5	—	0.1	—	0.1	—	0.1	
			24	4.5	—	0.36	—	0.44	—	0.5	
			75	5.5	—	—	—	1.65	—	—	
			50	5.5	—	—	—	—	—	1.65	
Input Leakage Current	I _I	V _{CC} or GND	5.5	—	±0.1	—	±1	—	±1	μA	
Quiescent Supply Current, SSI	I _{CC}	V _{CC} or GND	0	5.5	—	4	—	40	—	80	μA
Additional Quiescent Supply Current per Input Pin TTL Inputs High 1 Unit Load	ΔI _{CC}	V _{CC} -2.1		4.5 to 5.5		2.4	—	2.8	—	3	mA

#Test one output at a time for a 1-second maximum duration. Measurement is made by forcing current and measuring voltage to minimize power dissipation.

*Test verifies a minimum 50-ohm transmission-line-drive capability at +85°C, 75 ohms at +125°C.

ACT INPUT LOADING TABLE

INPUT	UNIT LOADS*
ALL	0.48

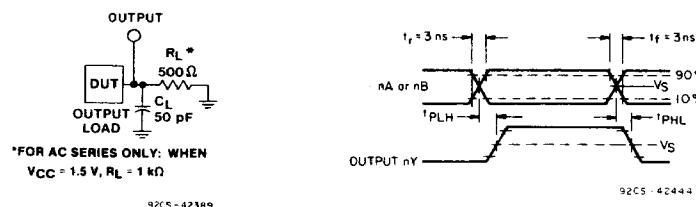
*Unit load is ΔI_{CC} limit specified in Static Characteristics Chart, e.g., 2.4 mA max. @ 25°C.

CD54/74AC86**CD54/74ACT86**SWITCHING CHARACTERISTICS: AC Series; $t_p, t_f = 3$ ns, $C_L = 50$ pF

CHARACTERISTICS	SYMBOL	V_{CC} (V)	AMBIENT TEMPERATURE (T_A) - °C				UNITS	
			-40 to +85		-55 to +125			
			MIN.	MAX.	MIN.	MAX.		
Propagation Delays: Input to Outputs	t_{PLH}	1.5	—	123	—	135	ns	
	t_{PHL}	3.3*	3.9	13.7	3.8	15.1		
		5†	2.8	9.8	2.7	10.8		
Power Dissipation Capacitance	$C_{PD\$}$	—	57 Typ.		57 Typ.		pF	
Input Capacitance	C_I	—	—	10	—	10	pF	

SWITCHING CHARACTERISTICS: ACT Series; $t_p, t_f = 3$ ns, $C_L = 50$ pF

CHARACTERISTICS	SYMBOL	V_{CC} (V)	AMBIENT TEMPERATURE (T_A) - °C				UNITS	
			-40 to +85		-55 to +125			
			MIN.	MAX.	MIN.	MAX.		
Propagation Delays: Input to Outputs	t_{PLH}	5†	3.8	13.3	3.7	14.6	ns	
	t_{PHL}							
Power Dissipation Capacitance	$C_{PD\$}$	—	57 Typ.		57 Typ.		pF	
Input Capacitance	C_I	—	—	10	—	10	pF	

*3.3 V: min. is @ 3.6 V
max. is @ 3 V†5 V: min. is @ 5.5 V
max. is @ 4.5 V\$ C_{PD} is used to determine the dynamic power consumption, per gate.For AC series: $P_D = V_{CC}^2 f_i (C_{PD} + C_L)$ For ACT series: $P_D = V_{CC}^2 f_i (C_{PD} + C_L) + V_{CC} \Delta I_{CC}$ where f_i = input frequency C_L = output load capacitance V_{CC} = supply voltage.

*FOR AC SERIES ONLY: WHEN

 $V_{CC} = 1.5$ V, $R_L = 1$ kΩ

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	CD54/74AC	CD54/74ACT
Input Level	V_{CC}	3 V
Input Switching Voltage, V_s	0.5 V_{CC}	1.5 V
Output Switching Voltage, V_s	0.5 V_{CC}	0.5 V_{CC}

Fig. 1 - Propagation delay times and test circuit.